
	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 1 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Annex A: Measurement data and plots


A.1 Spectrum analyser plots: CW, 80%AM, GSM and WCDMA signals

Please refer to Annex A.1 of the report number RTS-2337-1003-22 for the plots

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 2 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

A.2 Dipole validation and probe modulation factor plots

Please refer to Annex A.2 of the report number RTS-2337-1003-22 for probe modulation factor plots

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 3 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 1:19:04 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.5 V/m; Power Drift = 0.023 dB

Maximum value of Total (measured) = 166.2 V/m

E Scan - measurement distance from the probe sensor center to CD835

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 4 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 168.7 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.5 V/m; Power Drift = 0.023 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 160.3 M4	Grid 2 161.2 M4	Grid 3 146.0 M4
Grid 4 91.9 M4	Grid 5 91.9 M4	Grid 6 80.1 M4
Grid 7 168.7 M4	Grid 8 168.7 M4	Grid 9 146.6 M4

Author Data

Daoud Attayi

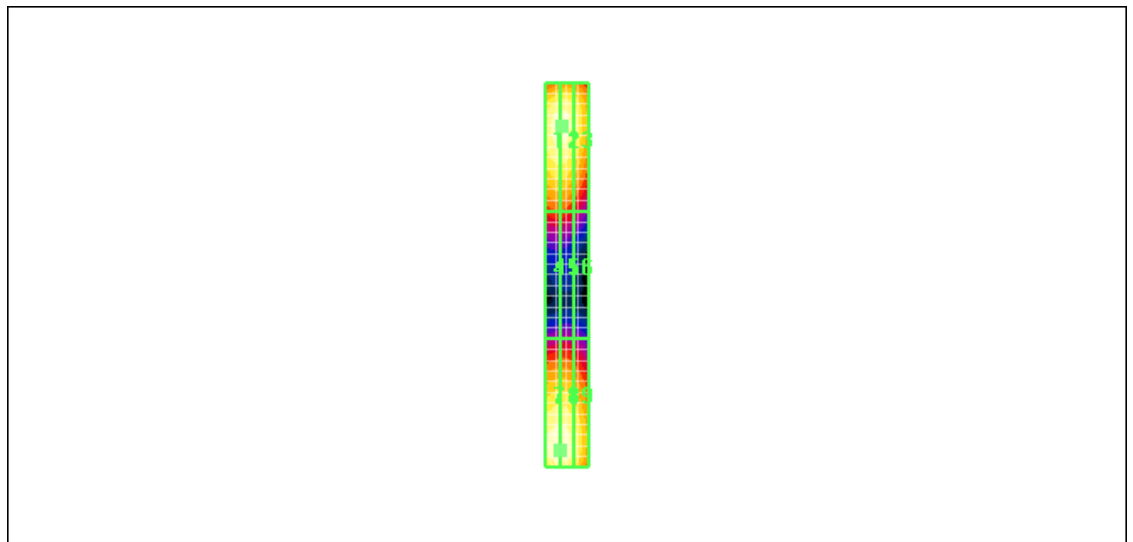
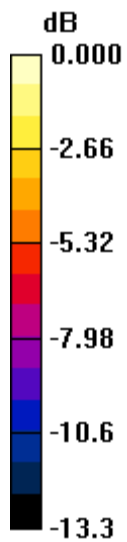
Dates of Test

August 09-11, 2010


Report No

RTS-2337-1008-32

FCC ID

L6ARDG70UW


0 dB = 168.7V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 6 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 1:31:19 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DAS4 (High Precision Assessment)

DAS4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DAS4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 141.6 V/m; Power Drift = 0.039 dB

Maximum value of Total (measured) = 126.4 V/m

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 7 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

dx=5mm, dy=5mm

Maximum value of peak Total field = 128.9 V/m

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

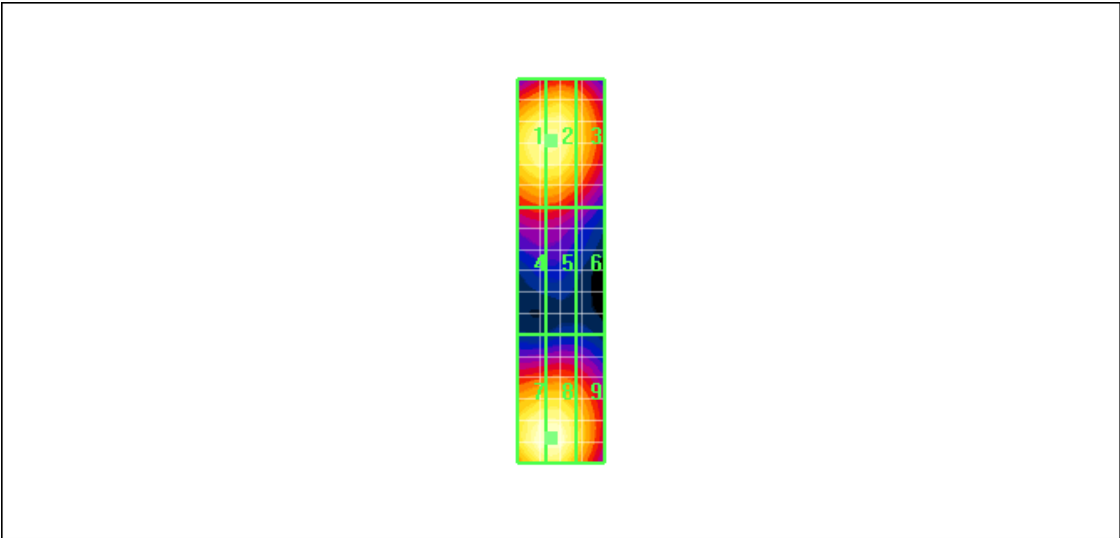
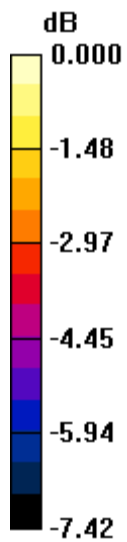
Reference Value = 141.6 V/m; Power Drift = 0.039 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)


Peak E-field in V/m

Grid 1 123.3 M2	Grid 2 123.4 M2	Grid 3 112.4 M2
Grid 4 90.8 M3	Grid 5 90.7 M3	Grid 6 81.4 M3
Grid 7 128.8 M2	Grid 8 128.9 M2	Grid 9 114.0 M2

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 8 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 128.9V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 9 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 1:50:25 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DAS4 (High Precision Assessment)

DAS4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DAS4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x13x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.506 A/m; Power Drift = 0.004 dB

Maximum value of Total (measured) = 0.478 A/m

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x121x1): Measurement grid:

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 10 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.489 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.506 A/m; Power Drift = 0.004 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.473 M4	Grid 2 0.476 M4	Grid 3 0.430 M4
Grid 4 0.486 M4	Grid 5 0.489 M4	Grid 6 0.438 M4
Grid 7 0.486 M4	Grid 8 0.488 M4	Grid 9 0.434 M4

Author Data

Daoud Attayi

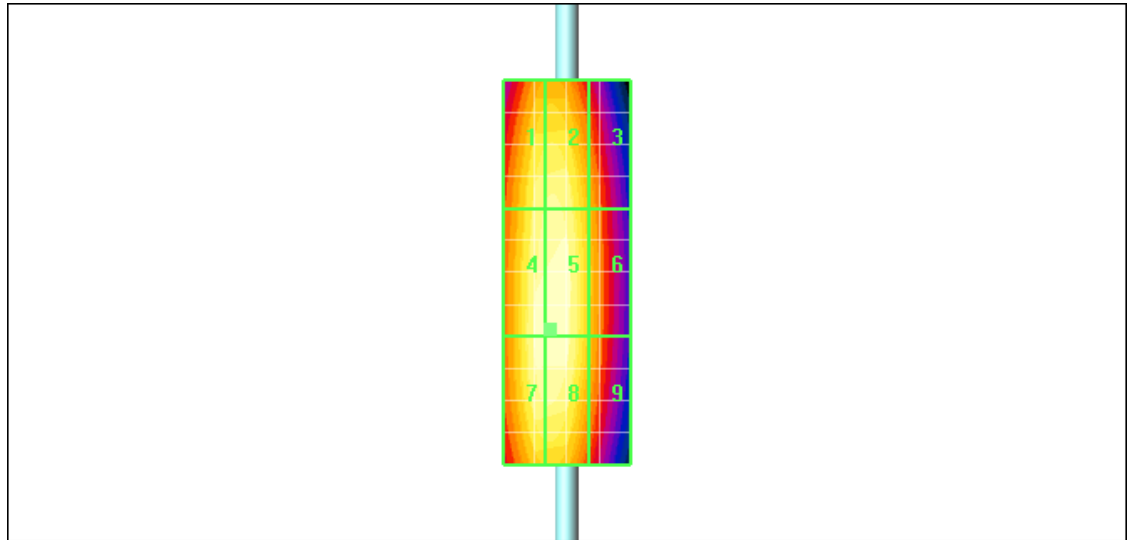
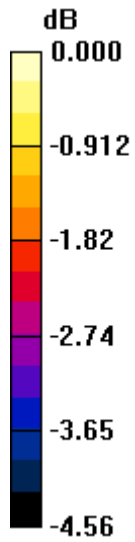
Dates of Test

August 09-11, 2010


Report No

RTS-2337-1008-32

FCC ID

L6ARDG70UW


0 dB = 0.489A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 12 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 1:45:33 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.476 A/m; Power Drift = 0.019 dB

Maximum value of Total (measured) = 0.450 A/m

H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 13 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.457 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.476 A/m; Power Drift = 0.019 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.437 M2	Grid 2 0.439 M2	Grid 3 0.397 M2
Grid 4 0.454 M2	Grid 5 0.457 M2	Grid 6 0.414 M2
Grid 7 0.445 M2	Grid 8 0.446 M2	Grid 9 0.403 M2

Author Data

Daoud Attayi

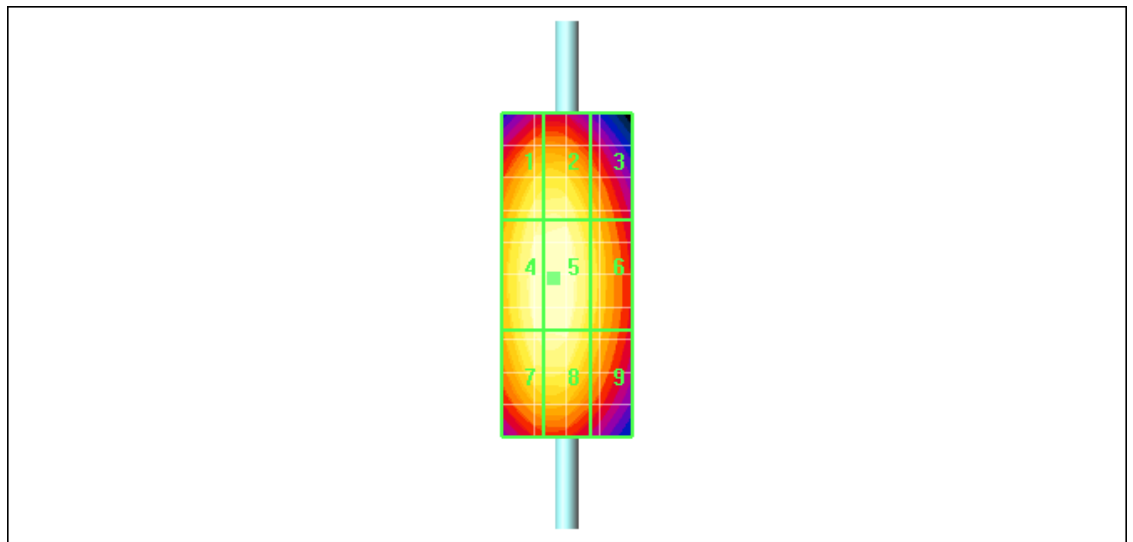
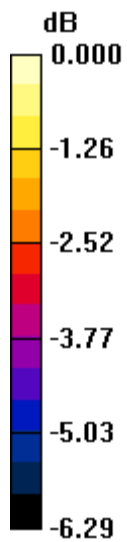
Dates of Test

August 09-11, 2010


Report No

RTS-2337-1008-32

FCC ID

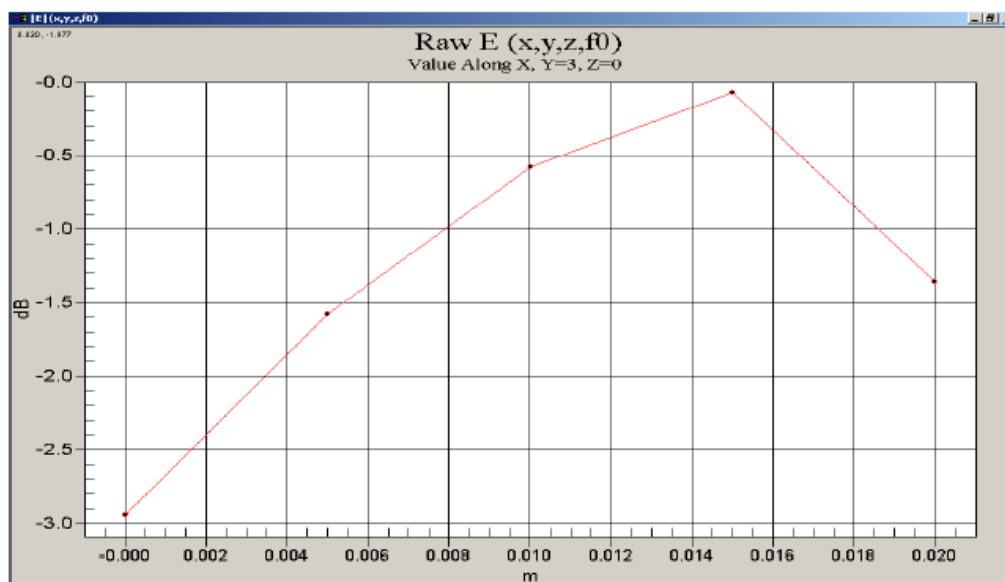
L6ARDG70UW


0 dB = 0.457A/m

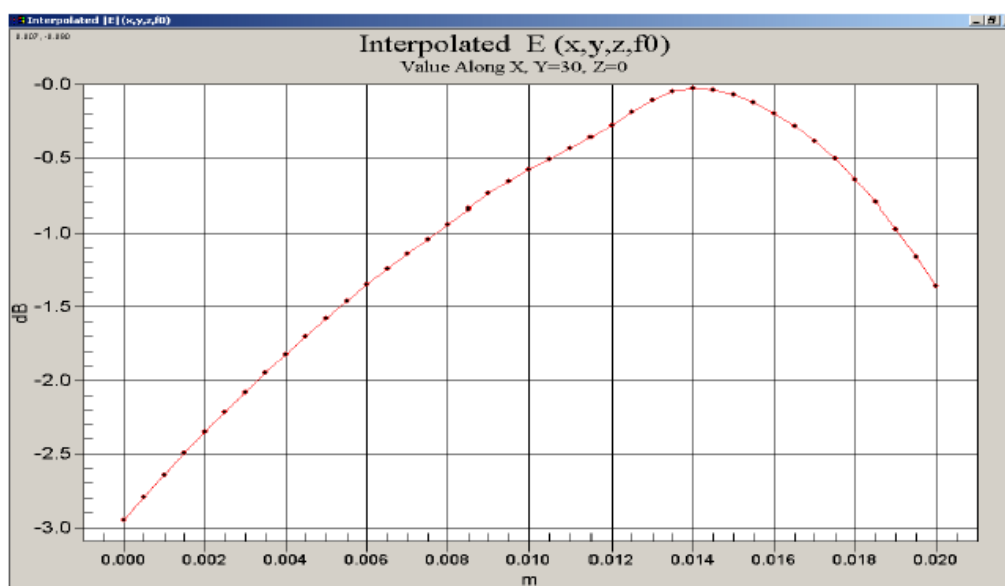
	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW			Page 15 (96)
	Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Justification of Step Size and Interpolation


This section demonstrates that a 5mm step size with interpolation provides sufficient resolution for RF emissions measurements. The DASY 4 uses interpolation algorithms to derive 9 interpolated points between every measured point.

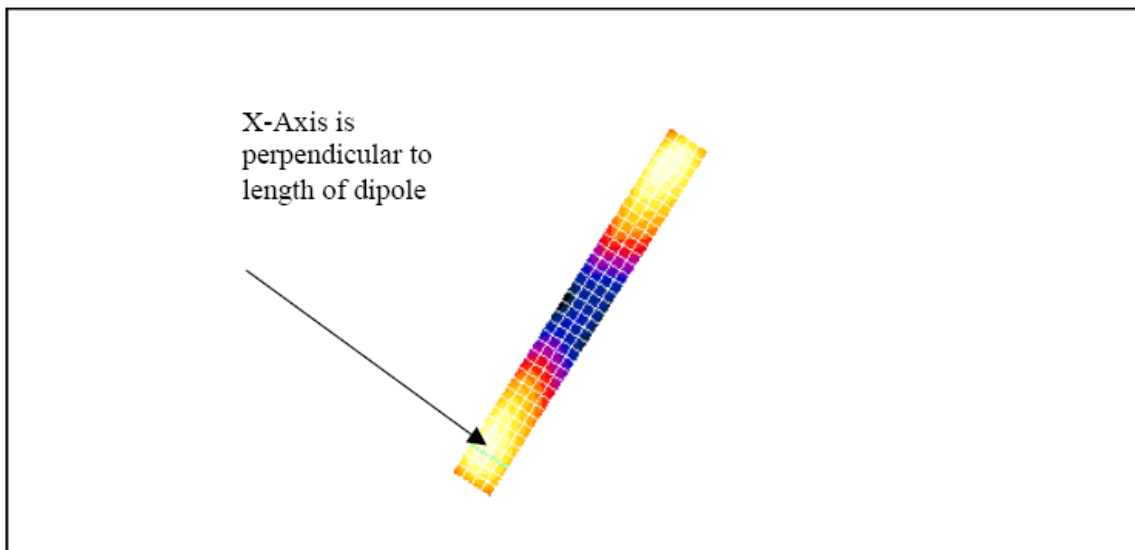


The figure above shows the raw measured field strength perpendicular to the length of the validation dipole. The TCB guidance slides require the 3dB width to be much larger than the step size. The width between -3dB points is > 21mm, at least 4 times the step size.



This figure shows the interpolated field strength perpendicular to the dipole. The interpolated points follow the raw points with no inconsistencies.


	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 16 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types (< 0.4% for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 17 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 14/07/2005 11:35:24 AM

Page 1 of 2

Date/Time: 14/07/2005 11:35:24 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of Total field (slot averaged) = 131.0 V/m


Hearing Aid Near-Field Category: M2 (AWF 0 dB)

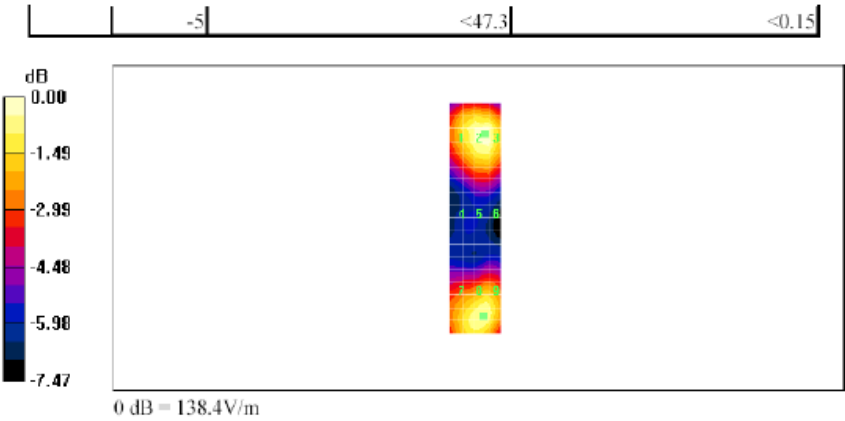
E in V/m (Time averaged) E in V/m (Slot averaged)


Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.2	138.1	138.4	123.2	138.1	138.4
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
80.9	92.3	92.2	80.9	92.3	92.2
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
119.8	131.0	130.7	119.8	131.0	130.7

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 18 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 19 (96)
	Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32
		FCC ID L6ARDG70UW	

Date/Time: 14/07/2005 11:44:51 AM

Page 1 of 2

Date/Time: 14/07/2005 11:44:51 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm
Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm
Maximum value of Total field (slot averaged) = 131.2 V/m


Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.1	138.6	138.6	123.1	138.6	138.6
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
81.4	92.1	91.6	81.4	92.1	91.6
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
121.3	131.2	131.0	121.3	131.2	131.0

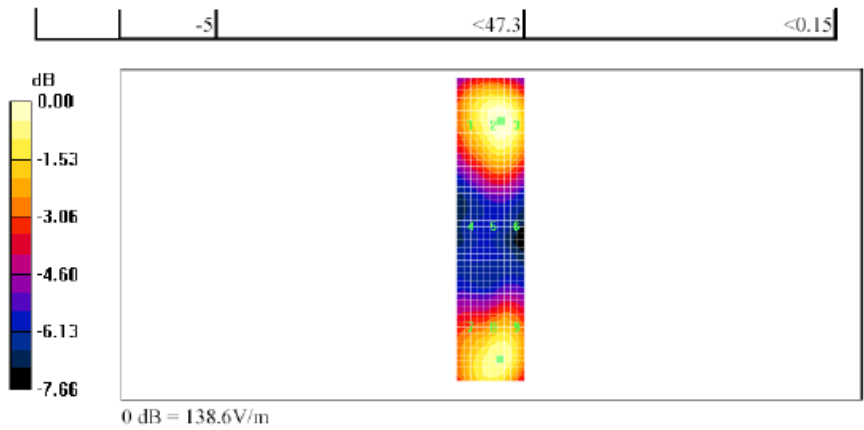
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 20 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 14/07/2005 11:44:51 AM

Page 2 of 2



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	Document			Page
	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW			21 (96)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	August 09-11, 2010	RTS-2337-1008-32	L6ARDG70UW	

Date/Time: 14/07/2005 12:43:02 PM

Page 1 of 2

Date/Time: 14/07/2005 12:43:02 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_5 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total field (slot averaged) = 0.406 A/m


Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
0.342	0.359	0.344	0.342	0.359	0.344
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
0.389	0.406	0.389	0.389	0.406	0.389
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
0.363	0.378	0.363	0.363	0.378	0.363

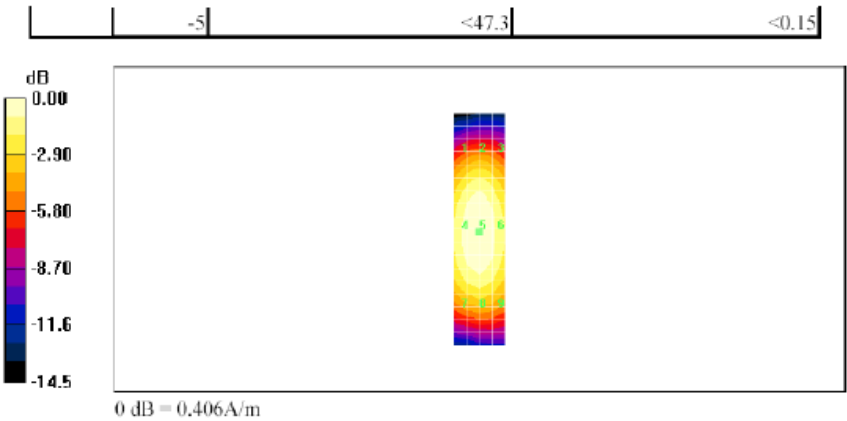
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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	Document			Page
	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW			22 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW	

Date/Time: 14/07/2005 12:43:02 PM

Page 2 of 2



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	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 23 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 14/07/2005 12:53:40 PM

Page 1 of 2

Date/Time: 14/07/2005 12:53:40 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_2 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total field (slot averaged) = 0.406 A/m


Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
0.347	0.361	0.348	0.347	0.361	0.348
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
0.394	0.406	0.391	0.394	0.406	0.391
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
0.367	0.380	0.365	0.367	0.380	0.365

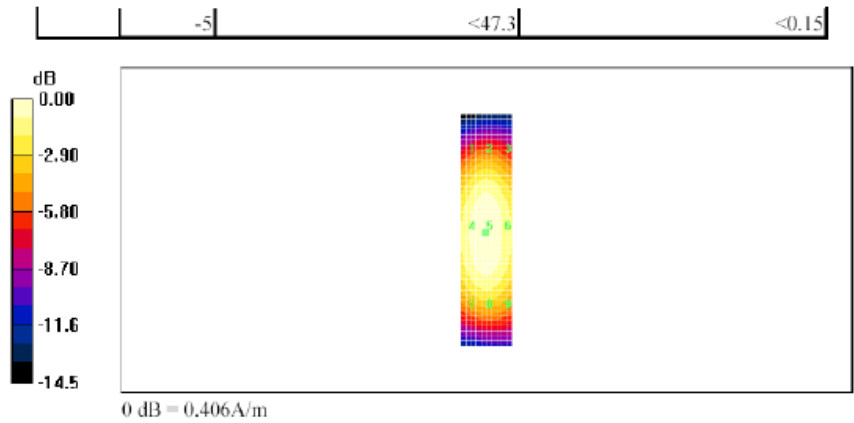
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

file://C:\Program%20Files\DASY4\Print_Templates\HAC_H_Dipole_CW%201880_2%... 14/07/2005


	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 24 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 14/07/2005 12:53:40 PM

Page 2 of 2



file:///C:/Program%20Files/DASY4/Print_Templates/HAC_H_Dipole_CW%201880_2%... 14/07/2005

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 25 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 4:53:50 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_850_low_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 59.0 V/m; Power Drift = 0.058 dB

Maximum value of Total (measured) = 48.3 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 137.3 V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 26 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Probe Modulation Factor = 2.84


Device Reference Point: 0.000, 0.000, -6.30 mm

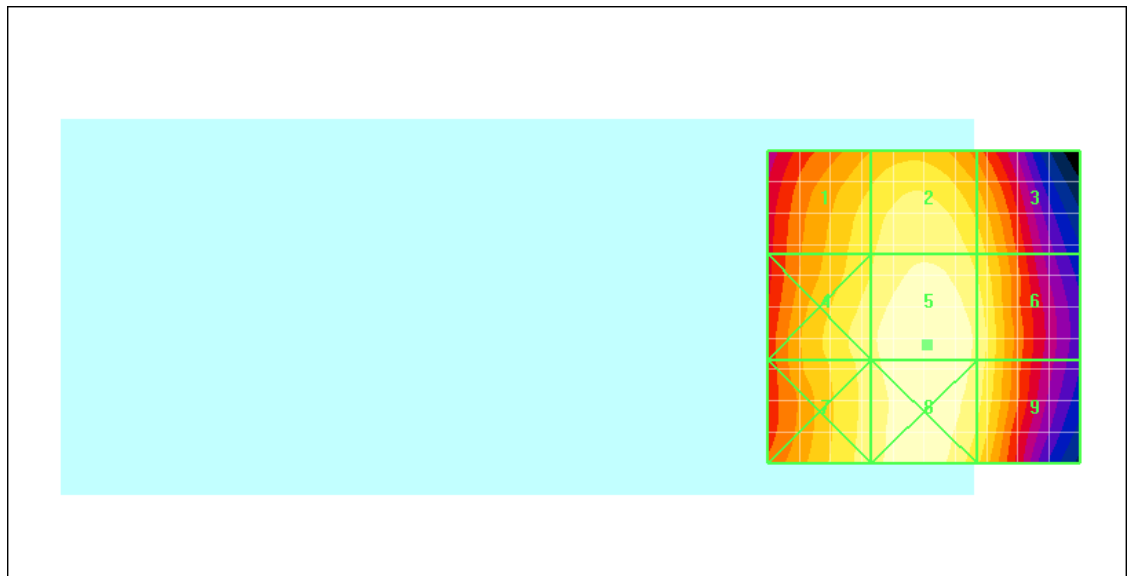
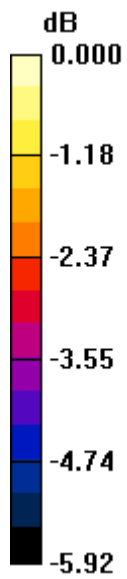
Reference Value = 59.0 V/m; Power Drift = 0.058 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)


Peak E-field in V/m

Grid 1 124.8 M4	Grid 2 130.4 M4	Grid 3 123.2 M4
Grid 4 130.1 M4	Grid 5 137.3 M4	Grid 6 129.8 M4
Grid 7 129.1 M4	Grid 8 136.8 M4	Grid 9 128.9 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 27 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 137.3V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 28 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 5:12:10 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_850_mid_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 59.1 V/m; Power Drift = -0.287 dB

Maximum value of Total (measured) = 45.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 29 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 130.9 V/m

Probe Modulation Factor = 2.84


Device Reference Point: 0.000, 0.000, -6.30 mm

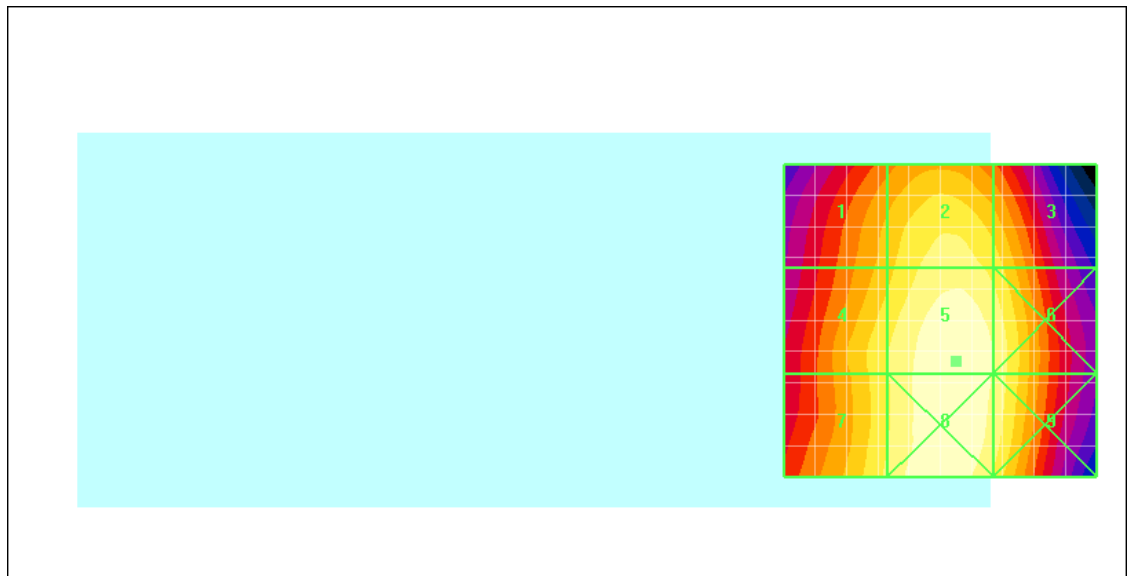
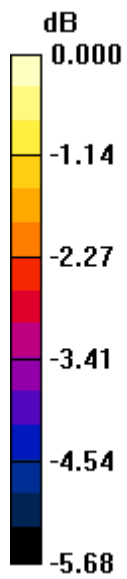
Reference Value = 59.1 V/m; Power Drift = -0.287 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)


Peak E-field in V/m

Grid 1 113.1 M4	Grid 2 122.9 M4	Grid 3 118.0 M4
Grid 4 119.9 M4	Grid 5 130.9 M4	Grid 6 125.1 M4
Grid 7 121.3 M4	Grid 8 130.7 M4	Grid 9 124.7 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 30 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 130.9V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 31 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 5:24:44 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_850_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 55.5 V/m; Power Drift = -0.017 dB

Maximum value of Total (measured) = 43.5 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 32 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 123.9 V/m

Probe Modulation Factor = 2.84


Device Reference Point: 0.000, 0.000, -6.30 mm

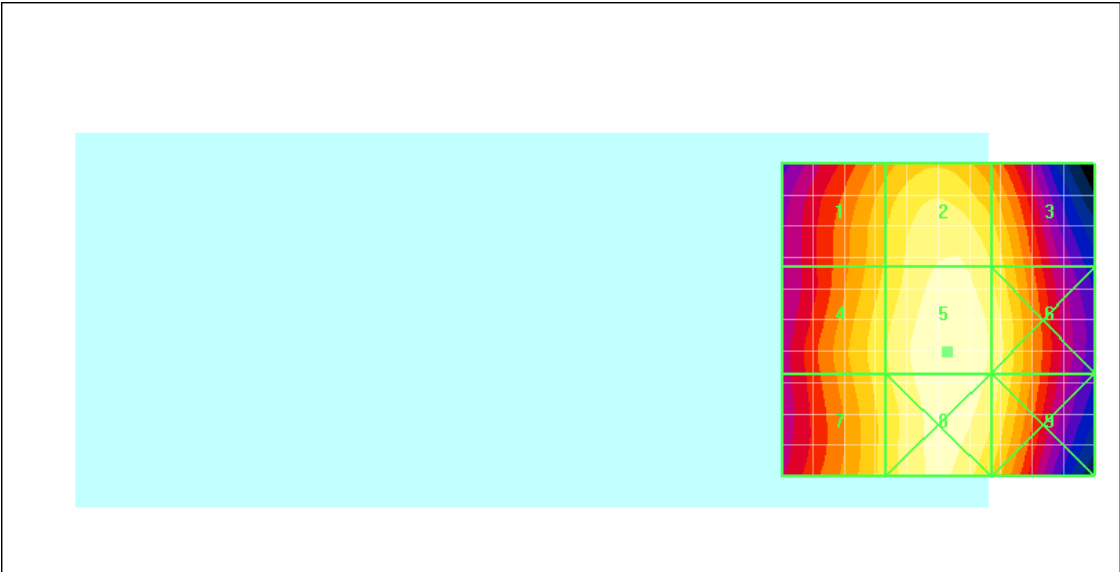
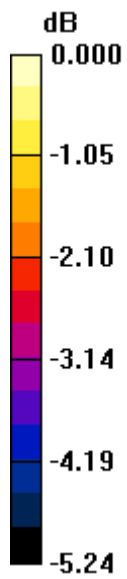
Reference Value = 55.5 V/m; Power Drift = -0.017 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)


Peak E-field in V/m

Grid 1 110.4 M4	Grid 2 119.8 M4	Grid 3 114.3 M4
Grid 4 114.0 M4	Grid 5 123.9 M4	Grid 6 118.5 M4
Grid 7 113.3 M4	Grid 8 123.3 M4	Grid 9 117.6 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 33 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 123.9V/m

	Document		Page
	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		34 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 7:11:59 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_850_low_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 58.9 V/m; Power Drift = -0.043 dB

Maximum value of Total (measured) = 46.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 35 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 130.8 V/m

Probe Modulation Factor = 2.84


Device Reference Point: 0.000, 0.000, -6.30 mm

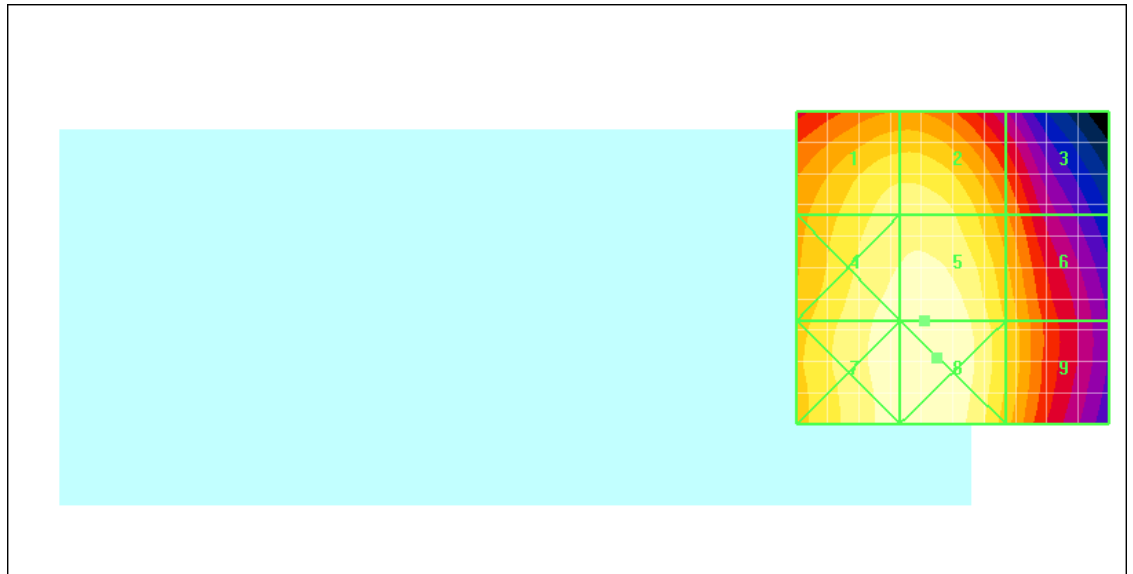
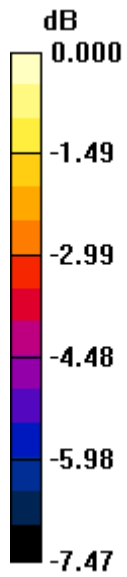
Reference Value = 58.9 V/m; Power Drift = -0.043 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)


Peak E-field in V/m

Grid 1 121.7 M4	Grid 2 121.9 M4	Grid 3 100.3 M4
Grid 4 129.2 M4	Grid 5 130.8 M4	Grid 6 110.6 M4
Grid 7 130.3 M4	Grid 8 132.1 M4	Grid 9 111.9 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 36 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 132.1V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 37 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 5:43:46 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_1900_low_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 13.5 V/m; Power Drift = -0.047 dB

Maximum value of Total (measured) = 25.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 38 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 62.8 V/m

Probe Modulation Factor = 2.66


Device Reference Point: 0.000, 0.000, -6.30 mm

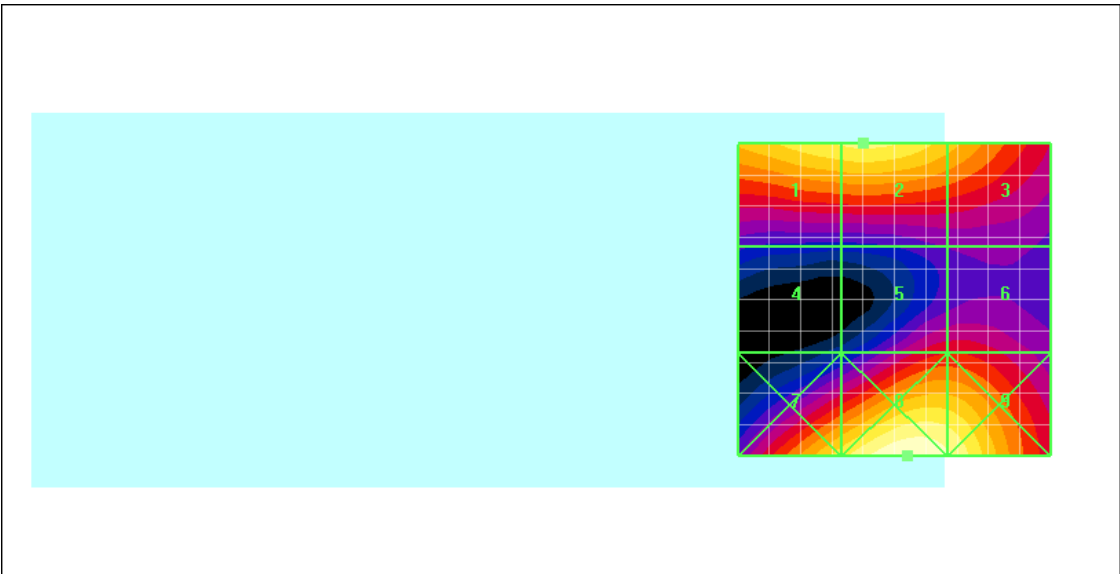
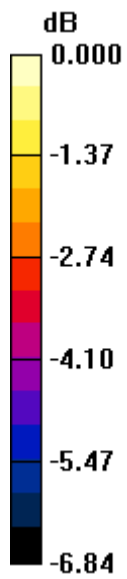
Reference Value = 13.5 V/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak E-field in V/m

Grid 1 62.3 M3	Grid 2 62.8 M3	Grid 3 57.3 M3
Grid 4 39.3 M4	Grid 5 47.5 M3	Grid 6 47.6 M3
Grid 7 61.0 M3	Grid 8 68.7 M3	Grid 9 65.9 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 39 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 68.7V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 40 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 5:54:41 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_1900_mid_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 17.8 V/m; Power Drift = 0.003 dB

Maximum value of Total (measured) = 26.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 41 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 62.7 V/m

Probe Modulation Factor = 2.66


Device Reference Point: 0.000, 0.000, -6.30 mm

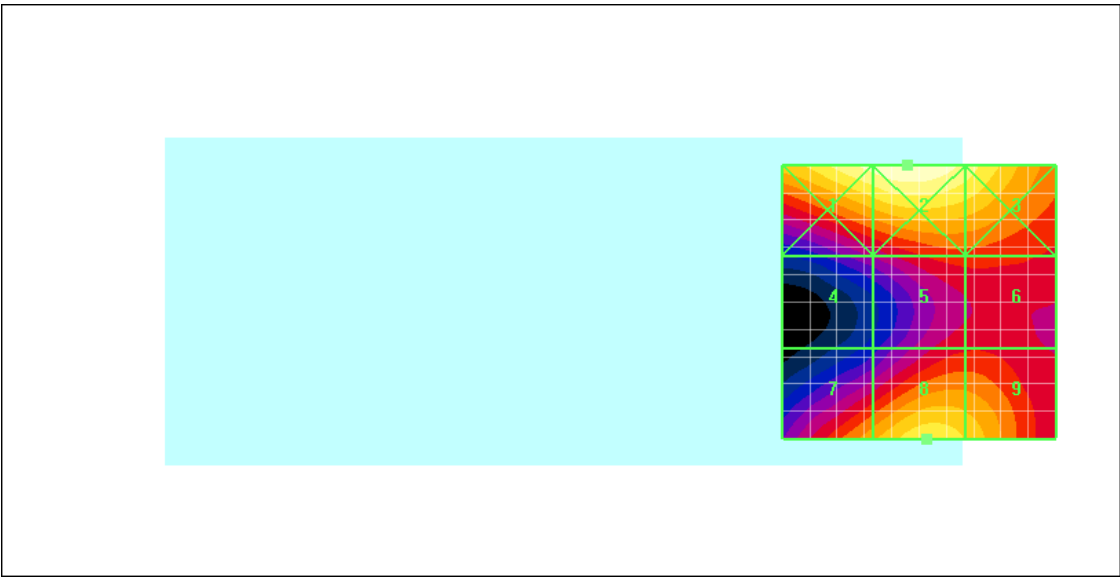
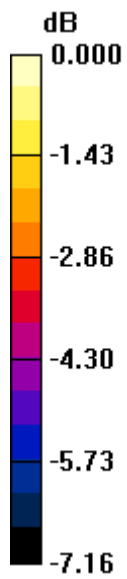
Reference Value = 17.8 V/m; Power Drift = 0.003 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak E-field in V/m

Grid 1 68.7 M3	Grid 2 70.8 M3	Grid 3 65.7 M3
Grid 4 43.7 M4	Grid 5 49.9 M3	Grid 6 49.9 M3
Grid 7 56.2 M3	Grid 8 62.7 M3	Grid 9 59.9 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 42 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 70.8V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 43 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 6:01:06 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_1900_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.1 V/m; Power Drift = -0.155 dB

Maximum value of Total (measured) = 26.3 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 44 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 55.9 V/m

Probe Modulation Factor = 2.66


Device Reference Point: 0.000, 0.000, -6.30 mm

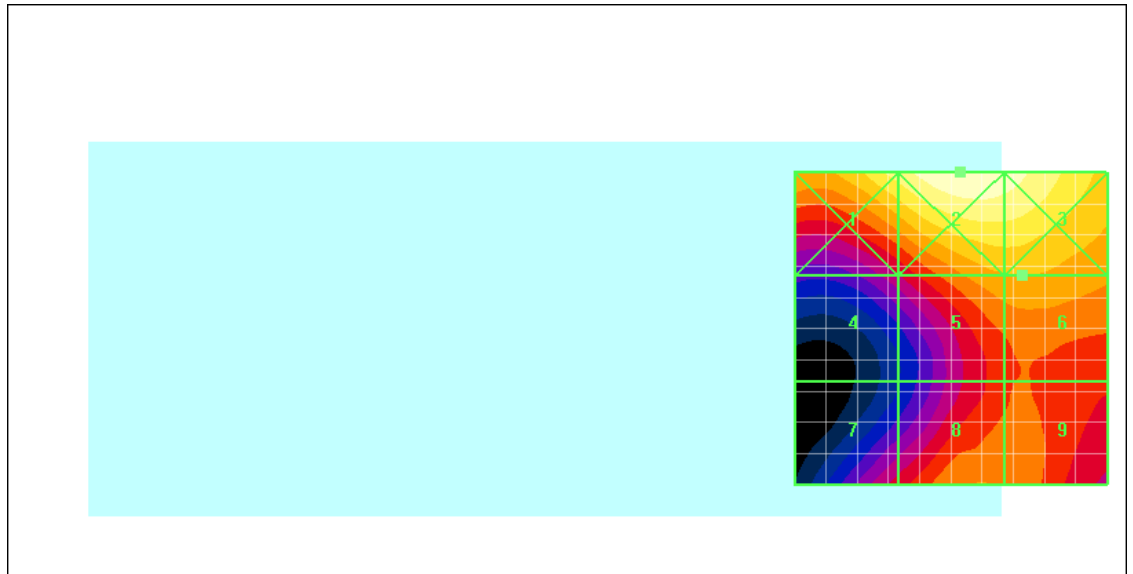
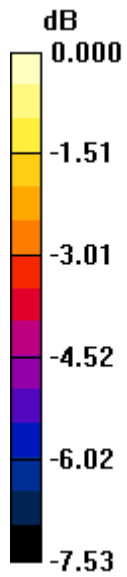
Reference Value = 20.1 V/m; Power Drift = -0.155 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak E-field in V/m

Grid 1 64.5 M3	Grid 2 70.3 M3	Grid 3 68.5 M3
Grid 4 44.1 M4	Grid 5 55.6 M3	Grid 6 55.9 M3
Grid 7 45.7 M4	Grid 8 52.9 M3	Grid 9 52.2 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 45 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 70.3V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 46 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 6:15:30 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_GSM_1900_low_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 13.4 V/m; Power Drift = -0.035 dB

Maximum value of Total (measured) = 26.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 47 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 58.3 V/m

Probe Modulation Factor = 2.66


Device Reference Point: 0.000, 0.000, -6.30 mm

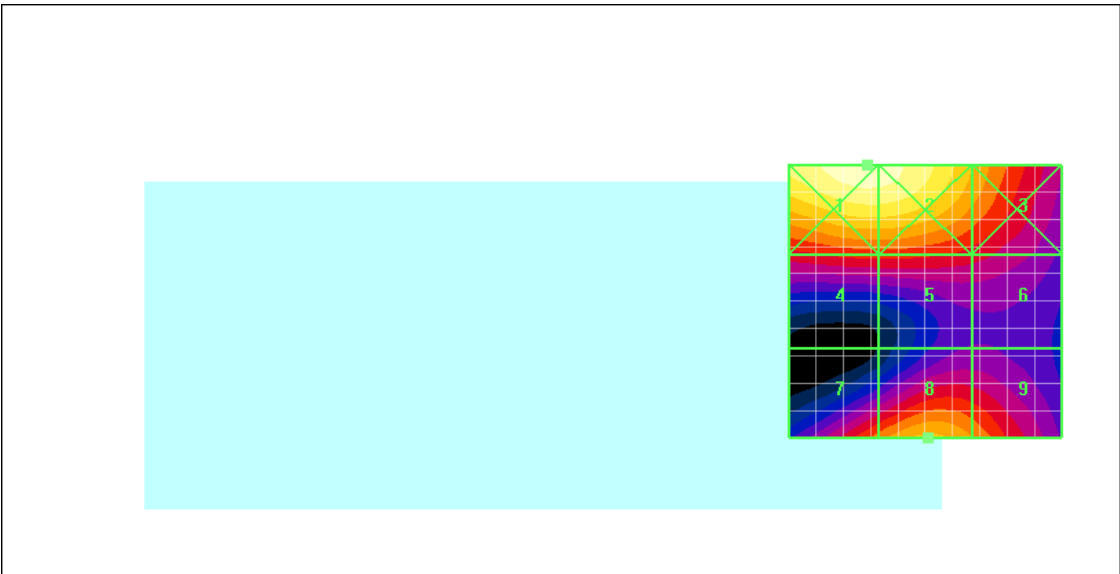
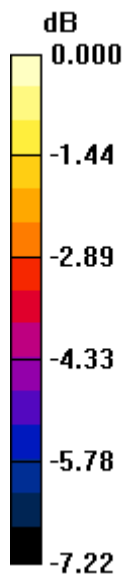
Reference Value = 13.4 V/m; Power Drift = -0.035 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak E-field in V/m

Grid 1 71.4 M3	Grid 2 70.8 M3	Grid 3 57.4 M3
Grid 4 49.7 M3	Grid 5 49.7 M3	Grid 6 47.3 M3
Grid 7 53.0 M3	Grid 8 58.3 M3	Grid 9 54.4 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 48 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 71.4V/m

	Document		Page
	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		49 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 6:35:53 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_UMTS_band_II_low_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.9 V/m; Power Drift = -0.223 dB

Maximum value of Total (measured) = 42.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 50 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 35.2 V/m

Probe Modulation Factor = 0.910

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.9 V/m; Power Drift = -0.223 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

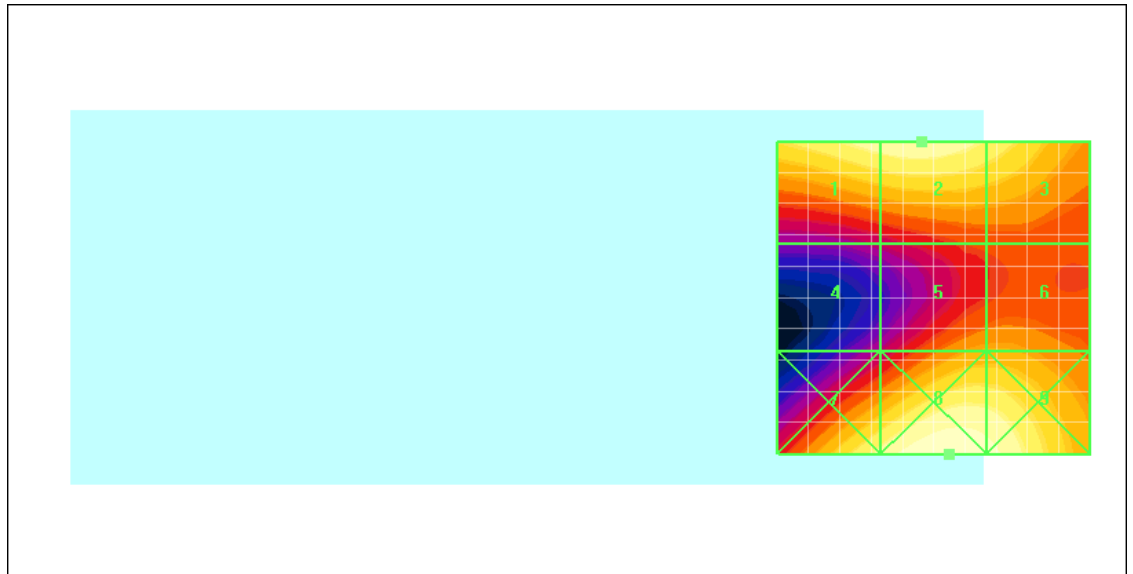
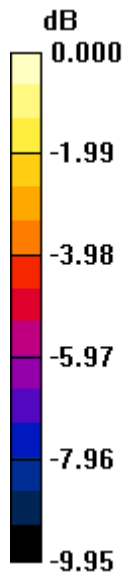
Grid 1 34.6 M4	Grid 2 35.2 M4	Grid 3 32.5 M4
Grid 4 19.6 M4	Grid 5 26.6 M4	Grid 6 26.6 M4
Grid 7 33.9 M4	Grid 8 38.5 M4	Grid 9 36.9 M4

Author Data
Daoud Attayi


Dates of Test
August 09-11, 2010

Report No
RTS-2337-1008-32

FCC ID
L6ARDG70UW



0 dB = 38.5V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 52 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 6:45:57 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_UMTS_band_II_mid_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.4 V/m; Power Drift = -0.044 dB

Maximum value of Total (measured) = 37.0 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 53 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 31.4 V/m

Probe Modulation Factor = 0.910

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.4 V/m; Power Drift = -0.044 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

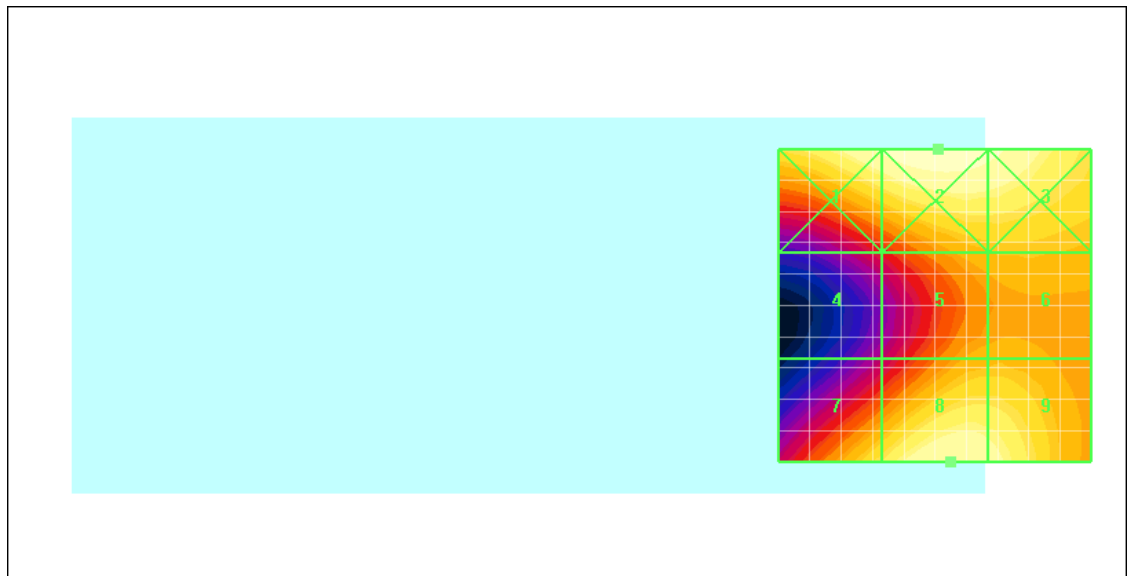
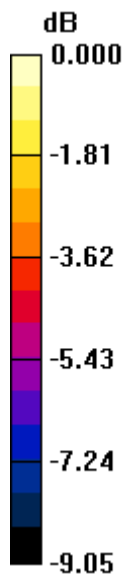
Grid 1 32.0 M4	Grid 2 33.7 M4	Grid 3 32.3 M4
Grid 4 19.8 M4	Grid 5 24.9 M4	Grid 6 25.1 M4
Grid 7 27.5 M4	Grid 8 31.4 M4	Grid 9 30.3 M4

Author Data
Daoud Attayi


Dates of Test
August 09-11, 2010

Report No
RTS-2337-1008-32

FCC ID
L6ARDG70UW



0 dB = 33.7V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 55 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 6:51:58 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_UMTS_band_II_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 28.8 V/m; Power Drift = -0.126 dB

Maximum value of Total (measured) = 40.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 56 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 28.9 V/m

Probe Modulation Factor = 0.910

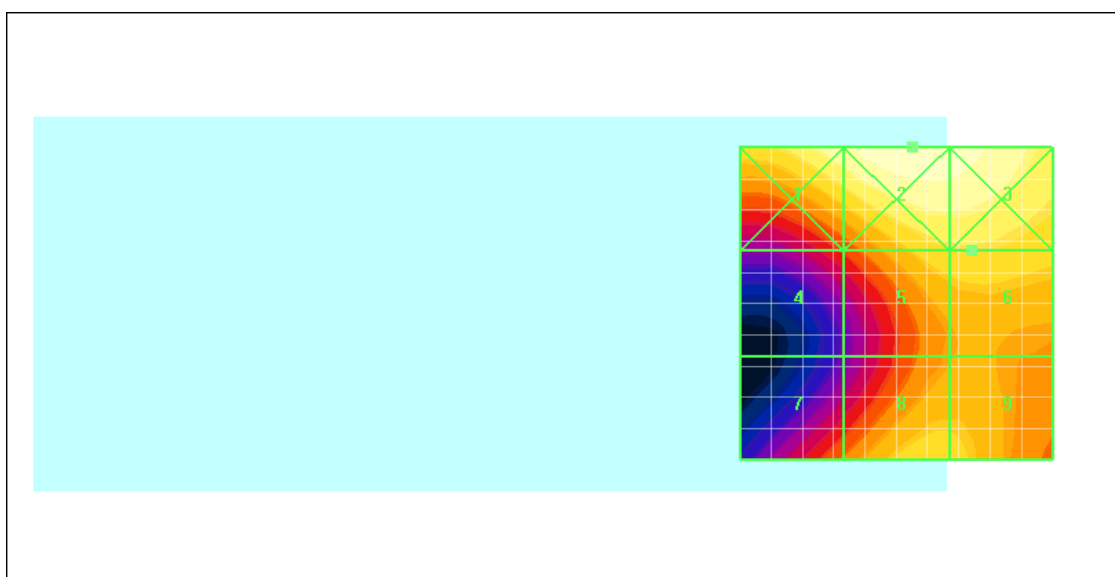
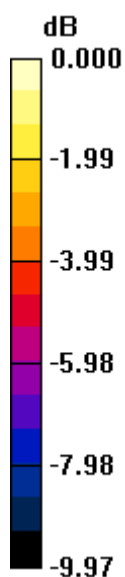
Device Reference Point: 0.000, 0.000, -6.30 mm


Reference Value = 28.8 V/m; Power Drift = -0.126 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)


Peak E-field in V/m

Grid 1 33.5 M4	Grid 2 36.7 M4	Grid 3 35.9 M4
Grid 4 21.6 M4	Grid 5 28.6 M4	Grid 6 28.9 M4
Grid 7 23.4 M4	Grid 8 28.1 M4	Grid 9 27.8 M4



	Document			Page
	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW			57 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW	

0 dB = 36.7V/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 58 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 7:00:04 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_E_UMTS_band_II_low_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 21.8 V/m; Power Drift = 0.083 dB

Maximum value of Total (measured) = 42.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 59 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 31.2 V/m

Probe Modulation Factor = 0.910


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 21.8 V/m; Power Drift = 0.083 dB


Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 38.4 M4	Grid 2 38.2 M4	Grid 3 31.5 M4
Grid 4 28.4 M4	Grid 5 28.5 M4	Grid 6 26.5 M4
Grid 7 27.5 M4	Grid 8 31.2 M4	Grid 9 29.5 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 60 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 61 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 8:26:28 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM850_low_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.038 A/m; Power Drift = -0.072 dB

Maximum value of Total (measured) = 0.080 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 62 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.158 A/m

Probe Modulation Factor = 2.79

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.038 A/m; Power Drift = -0.072 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

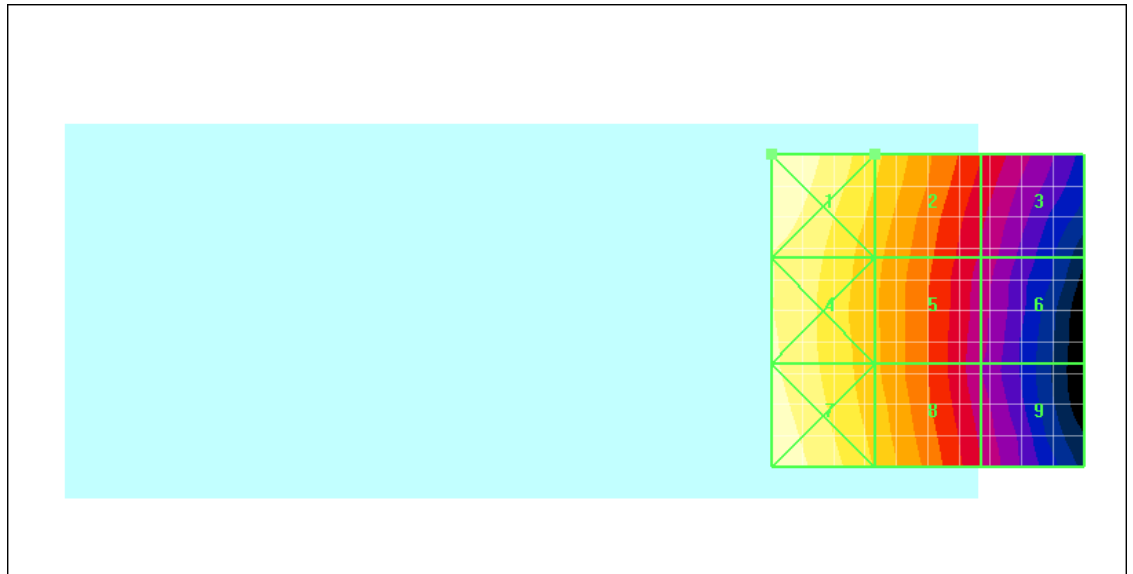
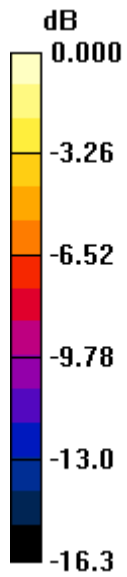
Grid 1 0.223 M4	Grid 2 0.158 M4	Grid 3 0.094 M4
Grid 4 0.201 M4	Grid 5 0.141 M4	Grid 6 0.081 M4
Grid 7 0.222 M4	Grid 8 0.152 M4	Grid 9 0.083 M4

Author Data
Daoud Attayi


Dates of Test
August 09-11, 2010

Report No
RTS-2337-1008-32

FCC ID
L6ARDG70UW



0 dB = 0.223A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 64 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 8:33:45 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM850_mid_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.040 A/m; Power Drift = -0.042 dB

Maximum value of Total (measured) = 0.082 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 65 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.230 A/m

Probe Modulation Factor = 2.79

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.040 A/m; Power Drift = -0.042 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

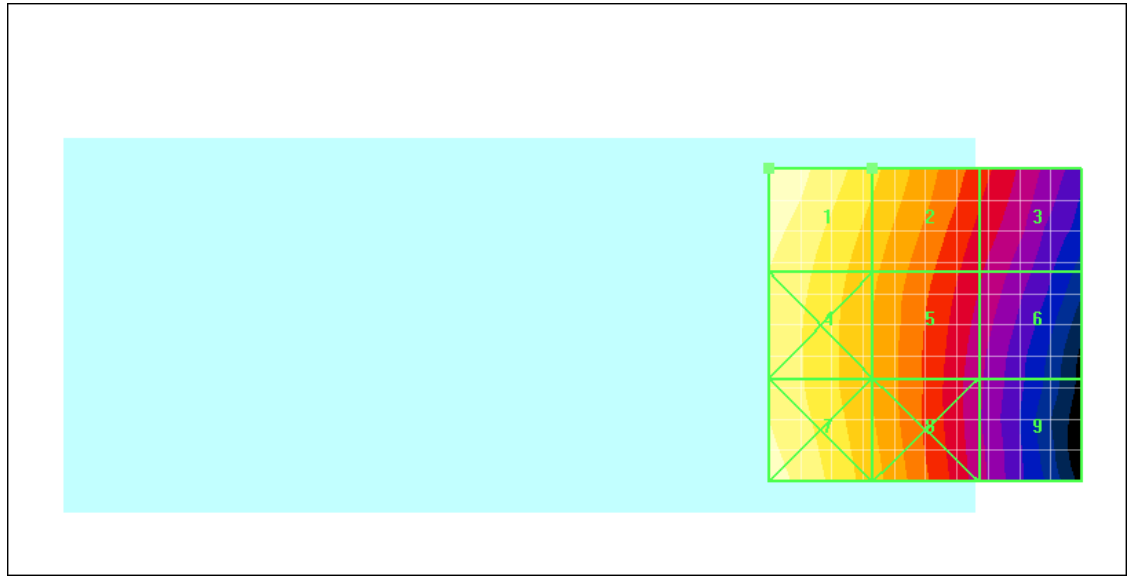
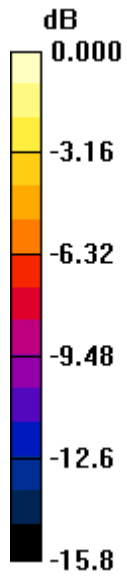
Grid 1 0.230 M4	Grid 2 0.165 M4	Grid 3 0.105 M4
Grid 4 0.203 M4	Grid 5 0.146 M4	Grid 6 0.089 M4
Grid 7 0.216 M4	Grid 8 0.149 M4	Grid 9 0.082 M4

Author Data
Daoud Attayi


Dates of Test
August 09-11, 2010

Report No
RTS-2337-1008-32

FCC ID
L6ARDG70UW



0 dB = 0.230A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 67 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 8:40:03 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM850_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.045 A/m; Power Drift = 0.225 dB

Maximum value of Total (measured) = 0.085 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 68 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.233 A/m

Probe Modulation Factor = 2.79


Device Reference Point: 0.000, 0.000, -6.30 mm

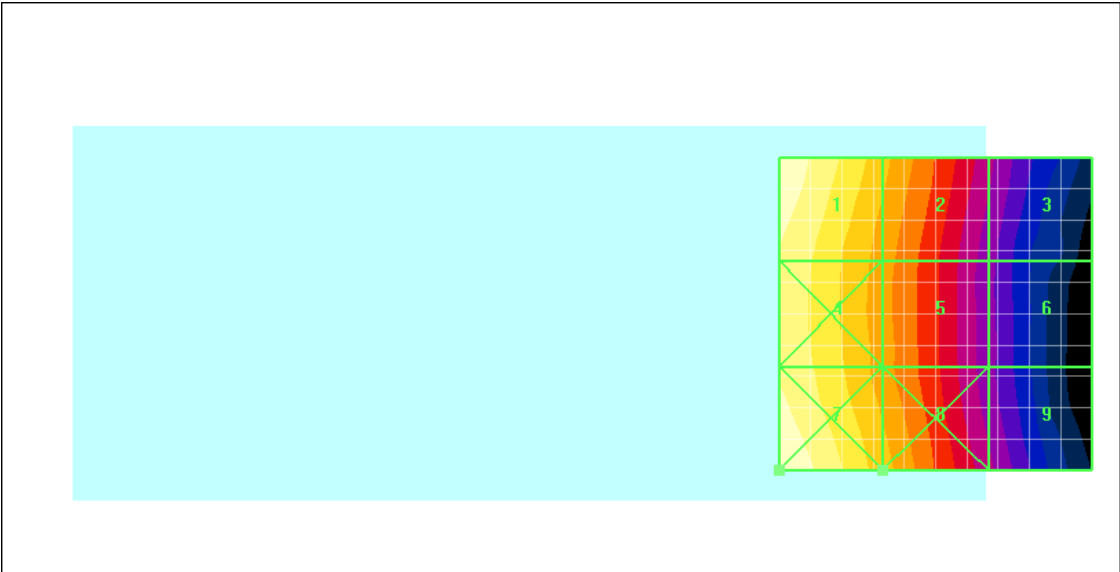
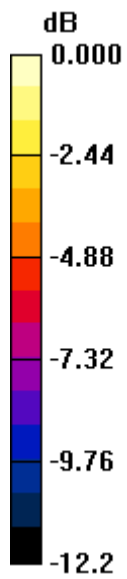
Reference Value = 0.045 A/m; Power Drift = 0.225 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)


Peak H-field in A/m

Grid 1 0.233 M4	Grid 2 0.168 M4	Grid 3 0.105 M4
Grid 4 0.213 M4	Grid 5 0.155 M4	Grid 6 0.097 M4
Grid 7 0.236 M4	Grid 8 0.169 M4	Grid 9 0.105 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 69 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.236A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 70 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 8:48:54 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM850_high_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.045 A/m; Power Drift = -0.086 dB

Maximum value of Total (measured) = 0.076 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 71 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.213 A/m

Probe Modulation Factor = 2.79


Device Reference Point: 0.000, 0.000, -6.30 mm

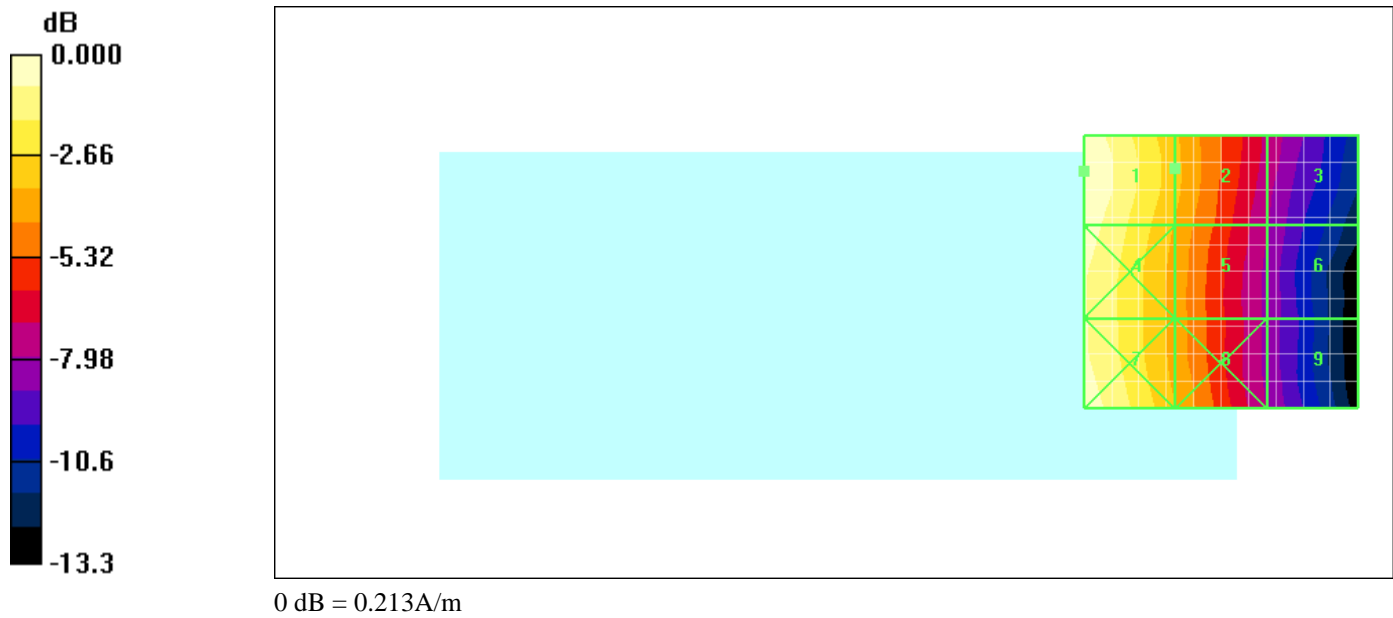
Reference Value = 0.045 A/m; Power Drift = -0.086 dB


Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.213 M4	Grid 2 0.147 M4	Grid 3 0.092 M4
Grid 4 0.203 M4	Grid 5 0.141 M4	Grid 6 0.086 M4
Grid 7 0.206 M4	Grid 8 0.143 M4	Grid 9 0.085 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 72 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 73 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 8:56:39 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM1900_low_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.067 A/m; Power Drift = 0.160 dB

Maximum value of Total (measured) = 0.066 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 74 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.160 A/m

Probe Modulation Factor = 2.42


Device Reference Point: 0.000, 0.000, -6.30 mm

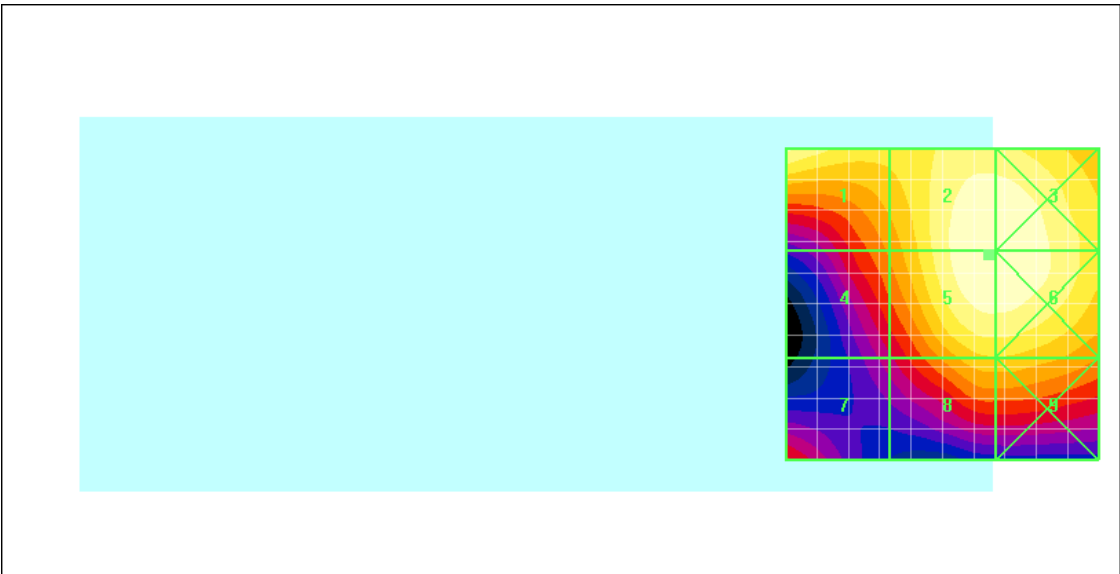
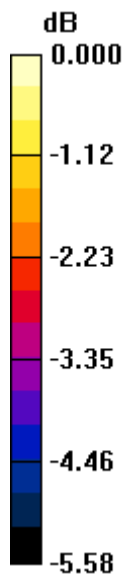
Reference Value = 0.067 A/m; Power Drift = 0.160 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak H-field in A/m

Grid 1 0.156 M3	Grid 2 0.160 M3	Grid 3 0.160 M3
Grid 4 0.130 M4	Grid 5 0.160 M3	Grid 6 0.160 M3
Grid 7 0.121 M4	Grid 8 0.140 M3	Grid 9 0.140 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 75 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.160A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 76 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:04:47 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM1900_mid_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.079 dB

Maximum value of Total (measured) = 0.083 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 77 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.173 A/m

Probe Modulation Factor = 2.42


Device Reference Point: 0.000, 0.000, -6.30 mm

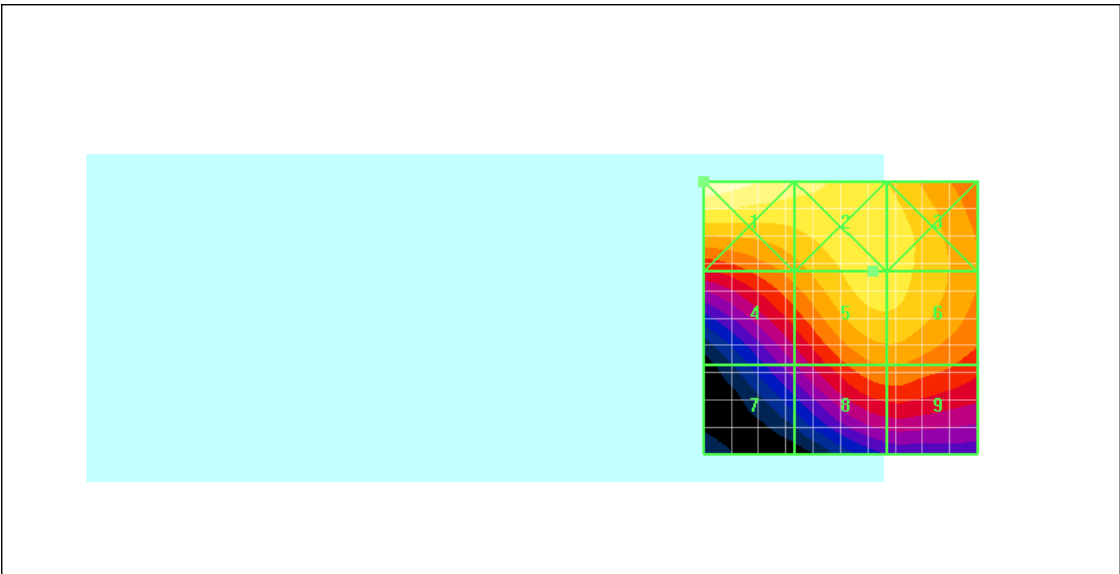
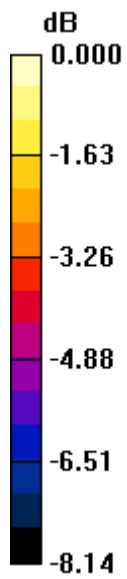
Reference Value = 0.073 A/m; Power Drift = -0.079 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak H-field in A/m

Grid 1 0.201 M3	Grid 2 0.181 M3	Grid 3 0.173 M3
Grid 4 0.151 M3	Grid 5 0.173 M3	Grid 6 0.172 M3
Grid 7 0.114 M4	Grid 8 0.148 M3	Grid 9 0.148 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 78 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.201A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 79 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:13:11 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM1900_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.180 dB

Maximum value of Total (measured) = 0.092 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 80 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.166 A/m

Probe Modulation Factor = 2.42

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.180 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

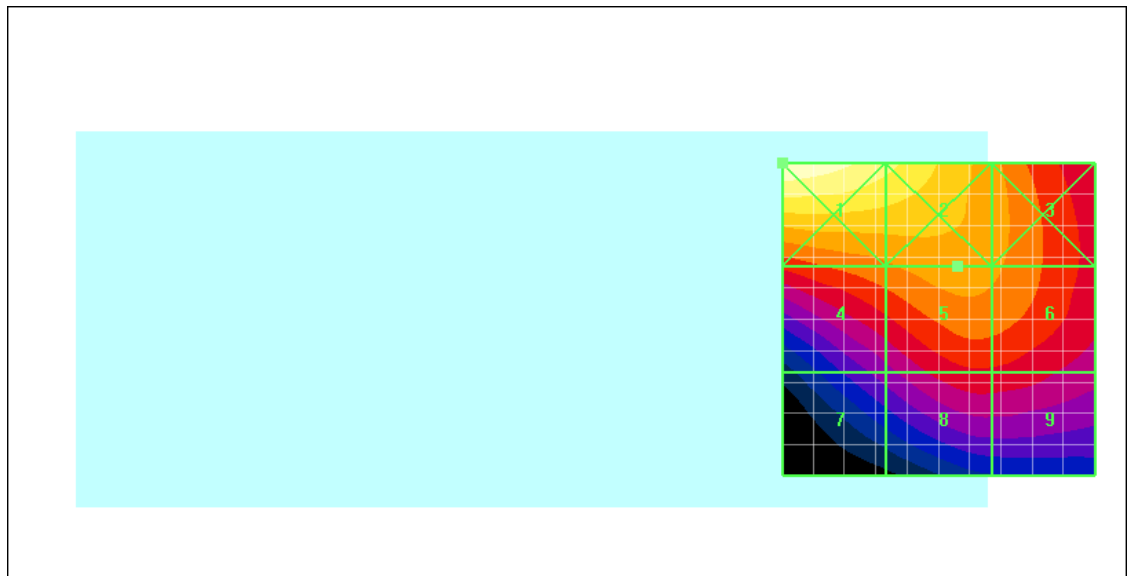
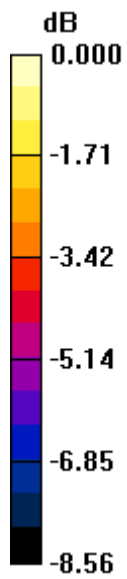
Grid 1 0.223 M3	Grid 2 0.200 M3	Grid 3 0.166 M3
Grid 4 0.159 M3	Grid 5 0.166 M3	Grid 6 0.163 M3
Grid 7 0.120 M4	Grid 8 0.140 M4	Grid 9 0.139 M4

Author Data
Daoud Attayi


Dates of Test
August 09-11, 2010

Report No
RTS-2337-1008-32

FCC ID
L6ARDG70UW



0 dB = 0.223A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 82 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:22:31 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_GSM1900_mid_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone;

Program Name: HAC RF H3DV6 Device

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.072 A/m; Power Drift = 0.222 dB

Maximum value of Total (measured) = 0.086 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 83 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.176 A/m

Probe Modulation Factor = 2.42


Device Reference Point: 0.000, 0.000, -6.30 mm

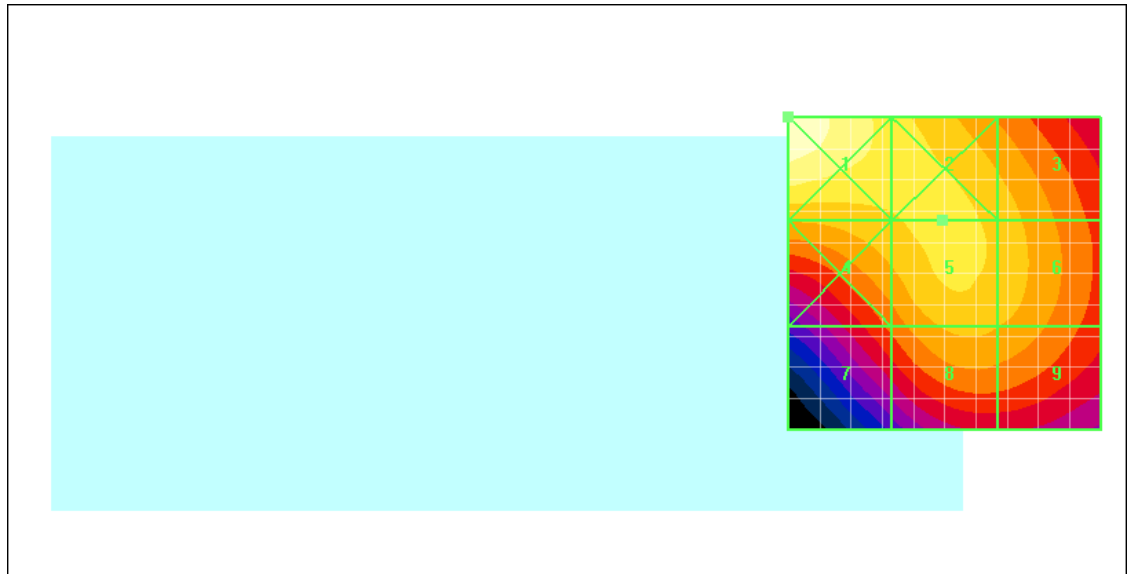
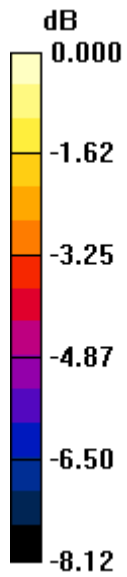
Reference Value = 0.072 A/m; Power Drift = 0.222 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)


Peak H-field in A/m

Grid 1 0.208 M3	Grid 2 0.180 M3	Grid 3 0.169 M3
Grid 4 0.171 M3	Grid 5 0.176 M3	Grid 6 0.170 M3
Grid 7 0.146 M3	Grid 8 0.165 M3	Grid 9 0.162 M3

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 84 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.208A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 85 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:35:27 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_UMTS_band_II_low_chan.da4](#)

DUT: BlackBerry Smartphone;

Program Name: HAC RF H3DV6 Device

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.111 A/m; Power Drift = -0.004 dB

Maximum value of Total (measured) = 0.106 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 86 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.104 A/m

Probe Modulation Factor = 0.970


Device Reference Point: 0.000, 0.000, -6.30 mm

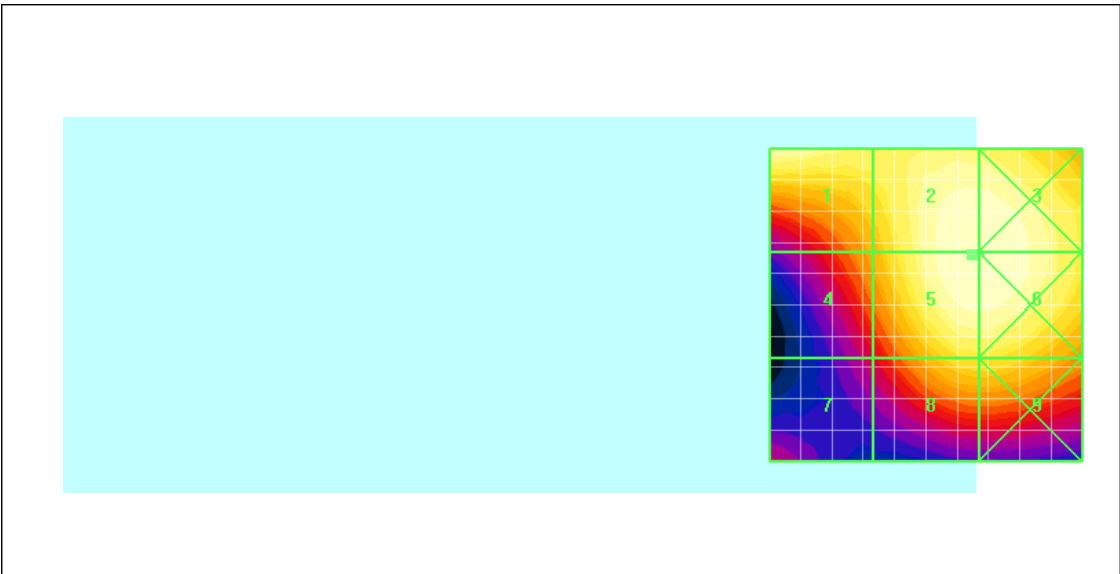
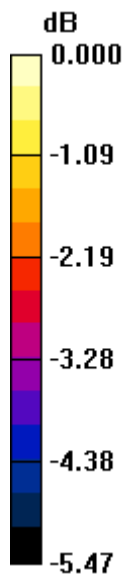
Reference Value = 0.111 A/m; Power Drift = -0.004 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)


Peak H-field in A/m

Grid 1 0.100 M4	Grid 2 0.103 M4	Grid 3 0.103 M4
Grid 4 0.086 M4	Grid 5 0.104 M4	Grid 6 0.103 M4
Grid 7 0.074 M4	Grid 8 0.092 M4	Grid 9 0.092 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 87 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.104A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 88 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:57:25 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_UMTS_band_II_mid_chan.da4](#)

DUT: BlackBerry Smartphone;

Program Name: HAC RF H3DV6 Device

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.101 A/m; Power Drift = -0.017 dB

Maximum value of Total (measured) = 0.114 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 89 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.096 A/m

Probe Modulation Factor = 0.970

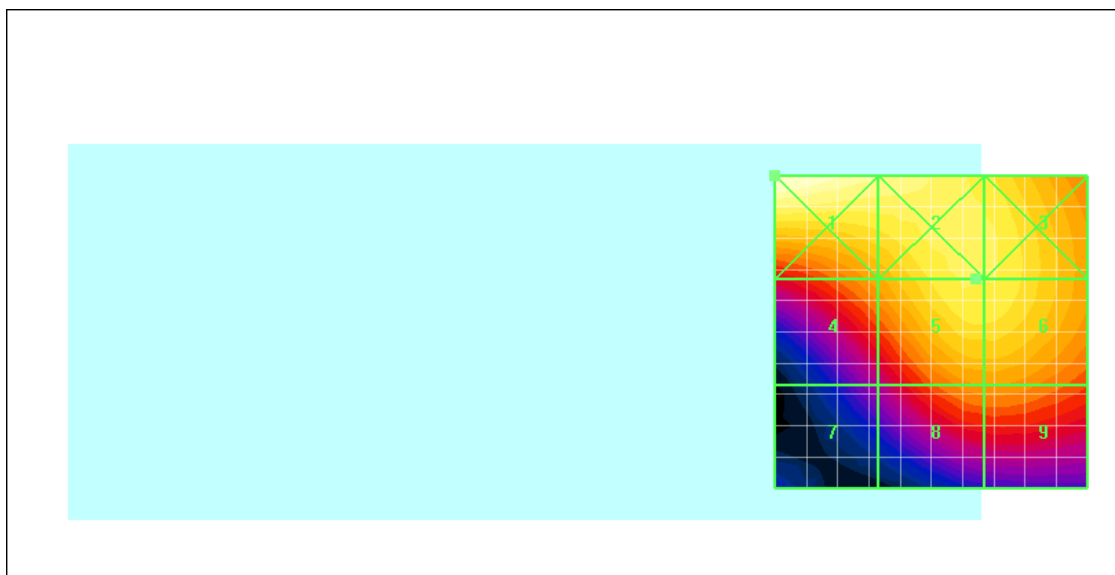
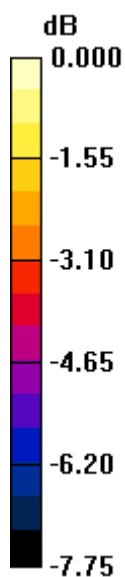
Device Reference Point: 0.000, 0.000, -6.30 mm


Reference Value = 0.101 A/m; Power Drift = -0.017 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)


Peak H-field in A/m

Grid 1 0.110 M4	Grid 2 0.101 M4	Grid 3 0.096 M4
Grid 4 0.084 M4	Grid 5 0.096 M4	Grid 6 0.096 M4
Grid 7 0.064 M4	Grid 8 0.082 M4	Grid 9 0.082 M4



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 90 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

0 dB = 0.110A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 91 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 10:04:20 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_UMTS_band_II_low_chan_Telecoil.da4](#)

DUT: BlackBerry Smartphone;

Program Name: HAC RF H3DV6 Device

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm


Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.110 A/m; Power Drift = -0.044 dB

Maximum value of Total (measured) = 0.106 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 92 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Maximum value of peak Total field = 0.101 A/m

Probe Modulation Factor = 0.970


Device Reference Point: 0.000, 0.000, -6.30 mm

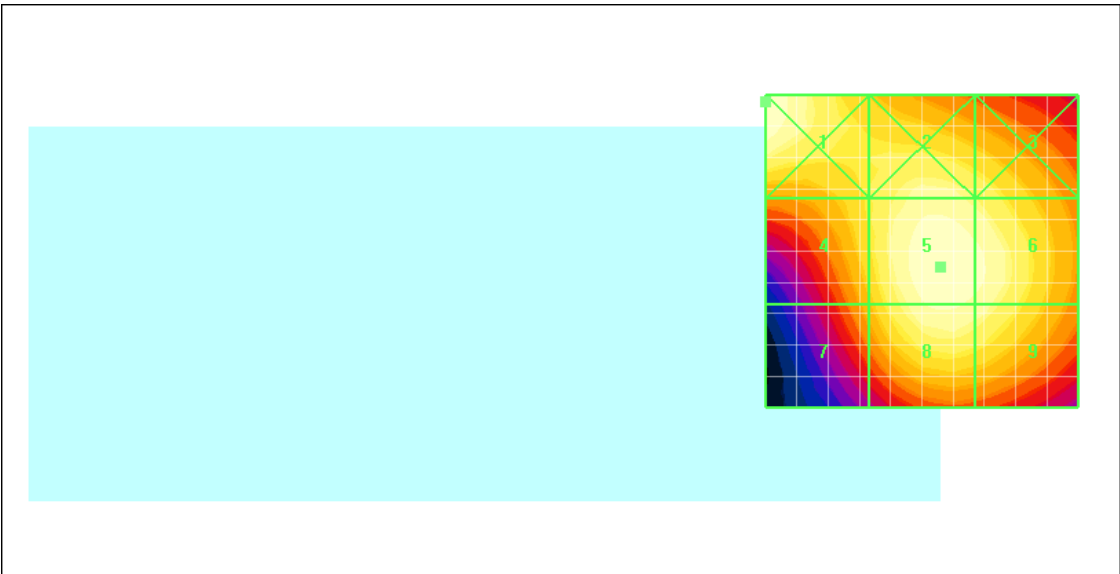
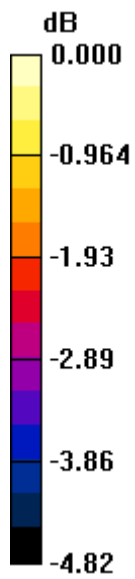
Reference Value = 0.110 A/m; Power Drift = -0.044 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)


Peak H-field in A/m

Grid 1 0.103 M4	Grid 2 0.098 M4	Grid 3 0.096 M4
Grid 4 0.093 M4	Grid 5 0.101 M4	Grid 6 0.100 M4
Grid 7 0.088 M4	Grid 8 0.100 M4	Grid 9 0.098 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 93 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.103A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 94 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Date/Time: 8/11/2010 9:50:22 PM

Test Laboratory: RIM Testing Services

File Name: [HAC_H_UMTS_band_II_high_chan.da4](#)

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00


Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.101 A/m; Power Drift = 0.001 dB

Maximum value of Total (measured) = 0.128 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.095 A/m

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 95 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW

Probe Modulation Factor = 0.970


Device Reference Point: 0.000, 0.000, -6.30 mm

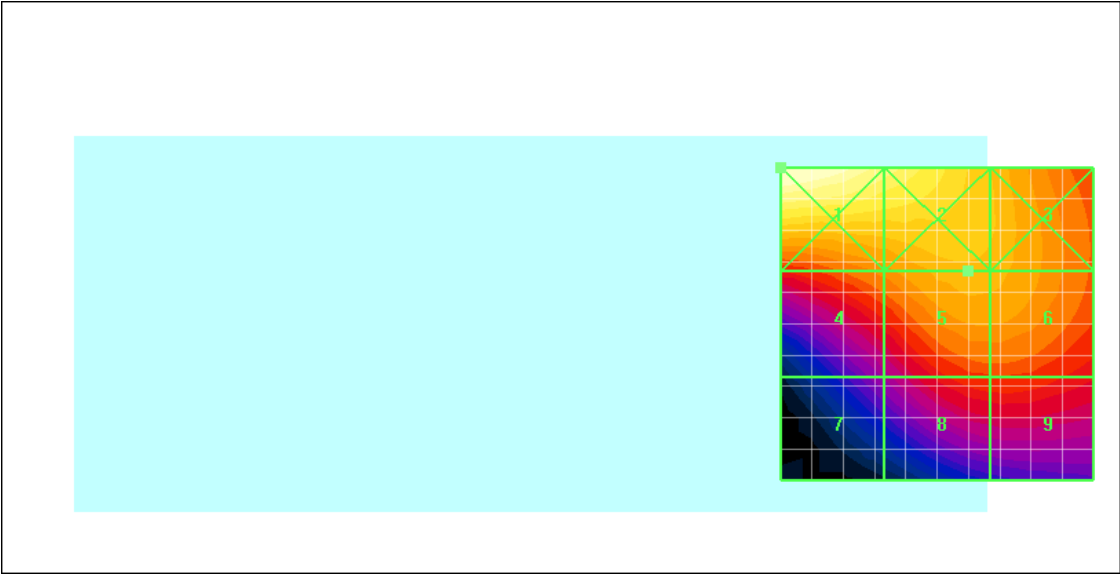
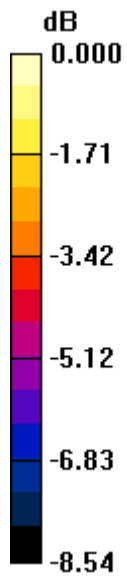
Reference Value = 0.101 A/m; Power Drift = 0.001 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.124 M4	Grid 2 0.111 M4	Grid 3 0.096 M4
Grid 4 0.088 M4	Grid 5 0.095 M4	Grid 6 0.094 M4
Grid 7 0.067 M4	Grid 8 0.081 M4	Grid 9 0.082 M4

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDG71UW		Page 96 (96)
Author Data Daoud Attayi	Dates of Test August 09-11, 2010	Report No RTS-2337-1008-32	FCC ID L6ARDG70UW



0 dB = 0.124A/m